

# STARPOWER

SEMICONDUCTOR

**FRED**

## FD200CCH60D1S

Molding Type Module

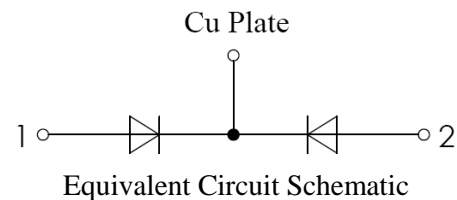
**600V/200A in one-package**

### General Description

STARPOWER Diode Power Module provides low forward voltage as well as low reverse recovery loss. They are designed for the applications such as SMPS.

### Features

- Fast soft diode
- Low forward voltage drop
- Small temperature coefficient
- Low reverse recovery losses
- High ruggedness
- Low inductance



### Typical Applications

- SMPS
- PFC
- Electric welders
- DC choppers

**Absolute Maximum Ratings**  $T_C=25^\circ\text{C}$  unless otherwise noted

Symbol	Description	FD200CCH60D1S	Units
$V_{RRM}$	Repetitive Peak Reverse Voltage	600	V
$V_{RSM}$	Non-repetitive Peak Reverse Voltage	600	V
$I_{FAV}$	Average Forward Current $T_C=100^\circ\text{C}$ , Diode $T_C=100^\circ\text{C}$ , Module	100	A
		200	
$I_{FSM}$	Surge Forward Current $V_R=0\text{V}$ , $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ $V_R=0\text{V}$ , $t_p=8.3\text{ms}$ , $T_j=25^\circ\text{C}$	1600	A
		1760	
$I^2t$	$I^2t$ -value $V_R=0\text{V}$ , $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ $V_R=0\text{V}$ , $t_p=8.3\text{ms}$ , $T_j=25^\circ\text{C}$	12800	$\text{A}^2\text{s}$
		12907	
$P_D$	Maximum Power Dissipation @ $T_j=150^\circ\text{C}$	579	W
$T_j$	Junction Temperature	-40 to +150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range	-40 to +125	$^\circ\text{C}$
M	Terminal Connection Torque, Screw M6	3.0 to 4.7	N.m
	Mounting Torque, Screw M4	1.0 to 1.5	
	Mounting Torque, Screw M6	3.0 to 4.7	

**Electrical Characteristics of Diode**  $T_C=25^\circ\text{C}$  unless otherwise noted

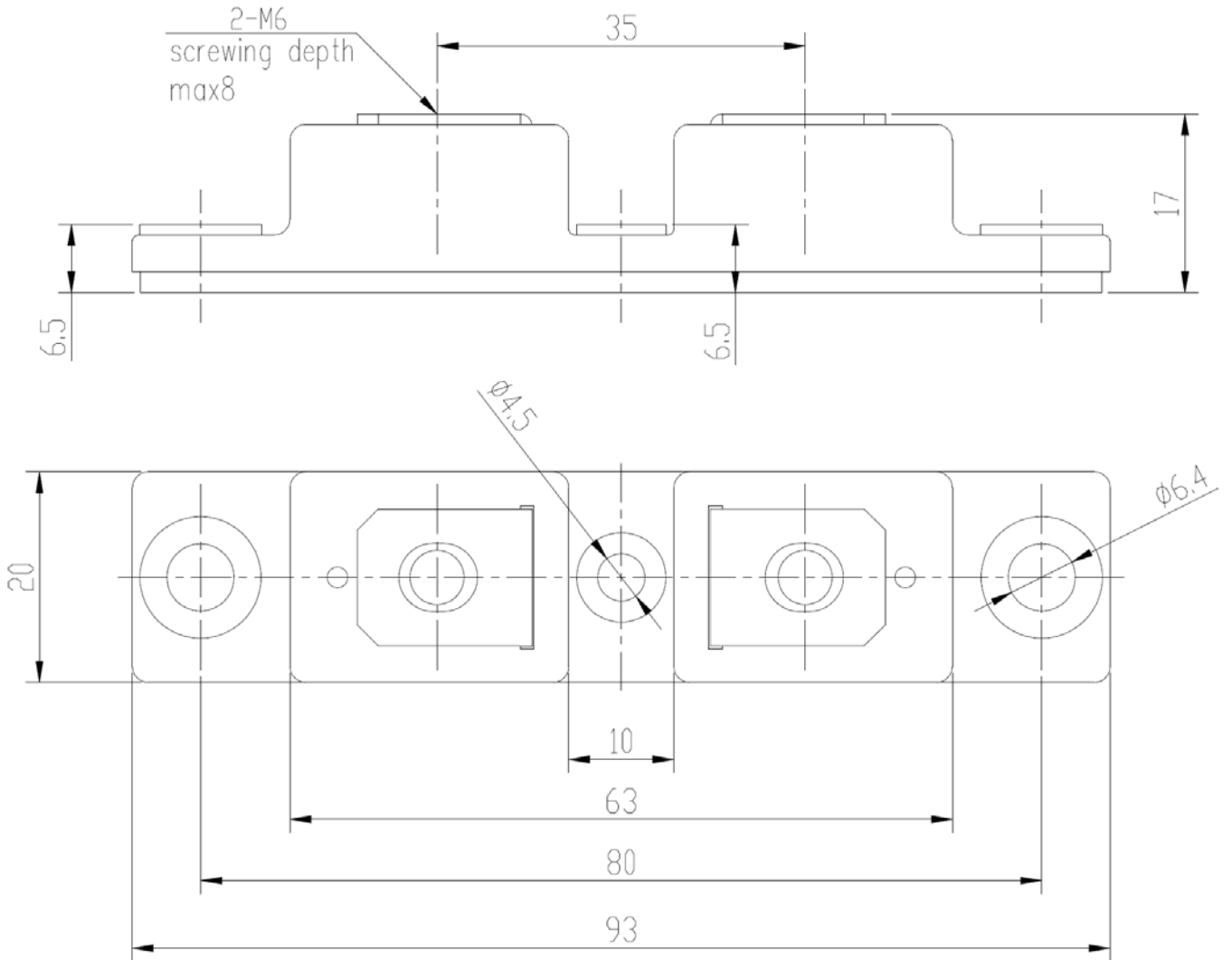
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$V_F$	Diode Forward Voltage	$I_F=100\text{A}$	$T_j=25^\circ\text{C}$	1.35	1.55	V
			$T_j=125^\circ\text{C}$	1.30	1.50	
$I_R$	Diode Reverse Current	$V_R=V_{RRM}$	$T_j=25^\circ\text{C}$		0.5	mA
			$T_j=125^\circ\text{C}$		1.0	
$t_{rr}$	Reverse Recovery Time	$I_F=100\text{A}$	$T_j=25^\circ\text{C}$	78		ns
			$T_j=125^\circ\text{C}$	145		
$I_{RM}$	Peak Reverse Recovery Current	$V_R=300\text{V}$ $di/dt=-200\text{A}/\mu\text{s}$	$T_j=25^\circ\text{C}$	7.8		A
			$T_j=125^\circ\text{C}$	15.2		
$Q_r$	Reverse Recovery Charge		$T_j=25^\circ\text{C}$	402		nC
			$T_j=125^\circ\text{C}$	1150		

**Thermal Characteristics**

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case		0.216	K/W
$R_{\theta CS}$	Case-to-Sink (Conductive grease applied)	0.06		K/W
Weight	Weight of Module	70		g

**Package Dimensions**

Dimensions in Millimeters



## Terms and Conditions of Usage

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This product data sheet is describing the characteristics of this product for which a warranty is granted. Any such warranty is granted exclusively pursuant the terms and conditions of the supply agreement. There will be no guarantee of any kind for the product and its characteristics.

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Should you intend to use the Product in aviation applications, in health or live endangering or life support applications, please notify.

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